

Sunday	Monday	Tuesday	Wednesday	Thursday	Friday
	<p>8h00 Foreword 8h15-9h45 <b>Weisbuch</b> III-N, why is it a special class of compound semiconductors?</p>	<p>8h00-9h30 <b>Auf der Maur</b> Modelization I</p>	<p>8h00-9h30 <b>Gayral</b> III-N polaritonics</p>	<p>8h30-10h00 <b>Boucaud</b> Basics of clean-room processing, specificities of III-Ns</p>	<p>8h30-10h00 <b>Strassburg</b> Optical devices, state-of-the-art and current trends</p>
	<p>10h00-11h30 <b>Grandjean</b> Growth I</p>	<p>9h45-11h15 <b>Matioli</b> Basics of III-N transistors</p>	<p>9h45-11h15 <b>Nemoz</b> Structural characterization I XRD</p>	<p>10h15-11h45 <b>Riechert</b> LEDs, lasers : basic physics</p>	<p>10h15-11h45 <b>Fernandez-Garrido</b> Nanowires : growth and optical properties</p>
	<p>11h45-12h15 Discussion Student group formation</p>	<p>11h30-12h00 Discussion</p>	<p>11h30-12h00 Discussion</p>	<p>11h45-12h15 Discussion</p>	<p>11h45-12h15 Discussion</p>
<b>LUNCH &amp; SPARE TIME</b>					
Bus from Grenoble to Autrans	<p>16h00-17h30 <b>Grandjean</b> Growth II</p>	<p>16h00-17h30 <b>Bechstedt</b> Polarization and QCSE in III-nitride heterostructures</p>	<p>17h00-18h30 <b>Bougerol</b> Structural characterization II TEM</p>	Excursion	
Installation at Escandilles	<p>17h45-19h15 <b>Gil</b> Fundamentals of semiconductor band structure, the case of III-Ns</p>	<p>17h45-19h15 <b>Auf der Maur</b> Modelization II</p>	<p>18h30-19h00 Discussion</p>		
	<b>DINNER</b>				
	20h30-21h00 Discussion	20h30-21h00 Discussion	Speakers dinner	20h30 Students presentations	